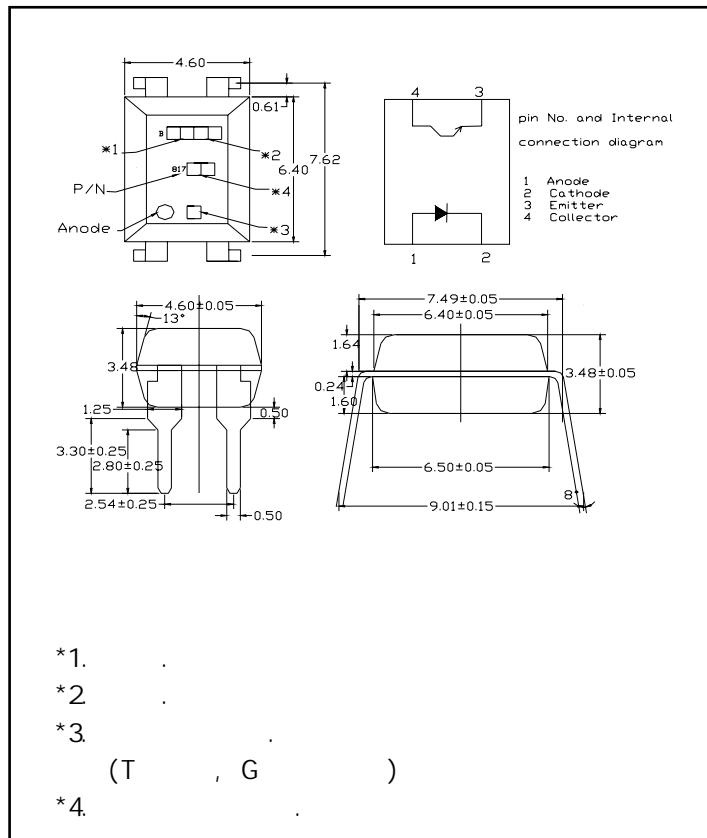


1. (CTR: .50% $I_F=5\text{mA}$,
 $V_{CE}=5\text{V}$)
2. ($V_{ISO}=5,000\text{Vrms}$)
3. (tr: TYP. $4\mu\text{s}$ $V_{CE}=2\text{V}$, $I_C=2\text{mA}$,
 $R_L=100\Omega$)
4. UL (.E236324)
5. CSA (.218896)
6. VDE (.40007240)
7. TUV (.R50029014)

● 1. BPC-817 GaAs
 NPN
 2. BPC-817 BIN 2.54mm

1.
 2.
 3.
 4.
 5.
- (=25)



		I_F	50 mA
		V_R	6 V
		P	70 mW
		V_{CEO}	35 V
		V_{ECO}	6 V
		I_C	50 mA
		P_C	150 mW
		P_{tot}	200 mW
*1		V_{iso}	5,000 Vrms
		V_{IOTM}	6,000 V
		V_{IORM}	630 V
		T_{opr}	-30 to + 100 °C
		T_{stg}	-55 to + 125 °C
*2		T_{sol}	260 °C

*1. , =40~60%

(1)
 (2)
 (3)

*2. 10

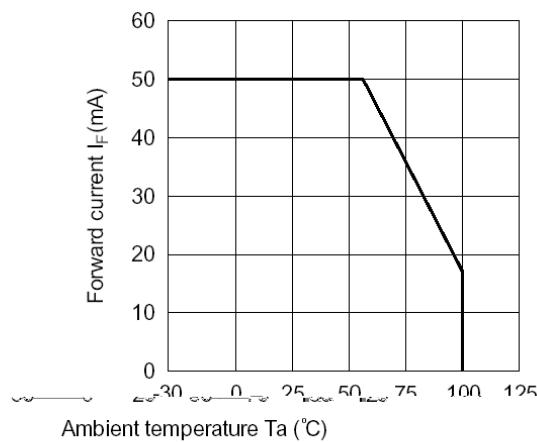
(-25)

				.	.		
	V _F	I _F =20mA	---	1.2	1.4	V	
	I _R	V _R =4V	---	---	10	μA	
	C _t	V=0, f=1KHz	---	30	250	pF	
	I _{CEO}	V _{CE} =20V, I _F =0	---	---	100	nA	
	BV _{CEO}	I _C =0.1mA I _F =0	35	---	---	V	
	BV _{ECO}	I _E =10μA I _F =0	6	---	---	V	
	I _c	I _F =5mA V _{CE} =5V	2.5	---	30	mA	
	CTR		50	---	600	%	
	V _{CE(sat)}	I _F =20mA I _C = 1mA	---	0.1	0.2	V	
	R _{iso}	DC500V 40~60%R.H.	5×10 ¹⁰	1×10 ¹¹	---		
	C _f	V=0, f=1MHz	---	0.6	1	pF	
	f _c	V _{CE} =5V, I _C =2mA R _L =100 , -3dB	---	80	---	kHz	
	t _r	V _{CE} =2V, I _C =2mA R _L =100	---	4	18	μs	
	t _f		---	3	18	μs	

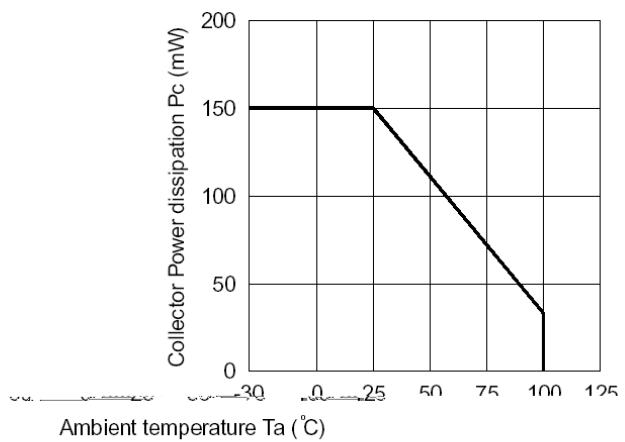
$$*1 = I_C / I_F \times 100\%$$

	. (%)	. (%)
L	50	100
A	80	160
B	130	260
C	200	400
D	300	600
L or A or B or C or D	50	600

**Fig.1 Forward Current
vs. Ambient Temperature**



**Fig.2 Collector Power Dissipation
vs. Ambient Temperature**



Forward Current vs. Forward Voltage

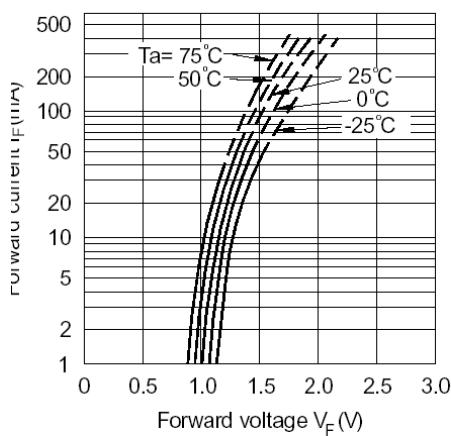


Fig.3 Collector-emitter Saturation Voltage vs. Forward Current

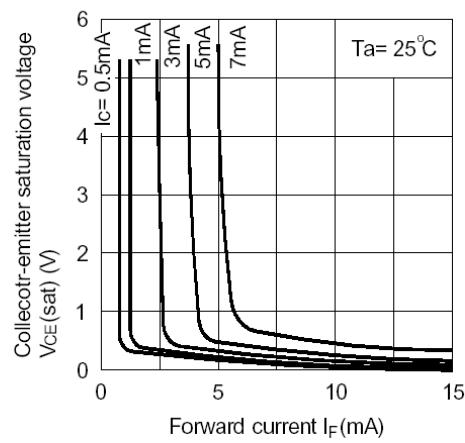
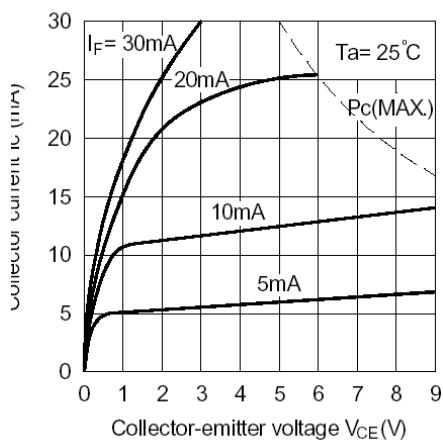


Fig.4

Forward current I_F (mA)

**Collector Current vs.
Collector-emitter Voltage**



**Fig.5 Current Transfer Ratio vs.
Forward Current**

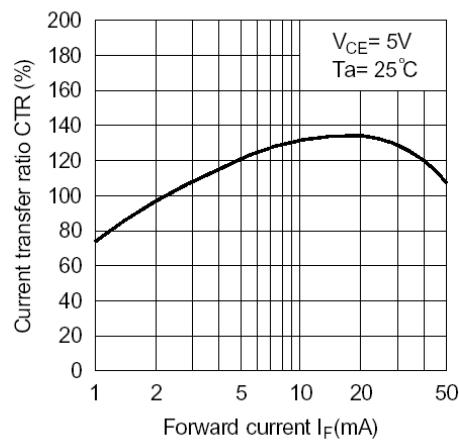


Fig.6

Collector current I_C (mA)

Fig.7 Relative Current Transfer Ratio vs. Ambient Temperature

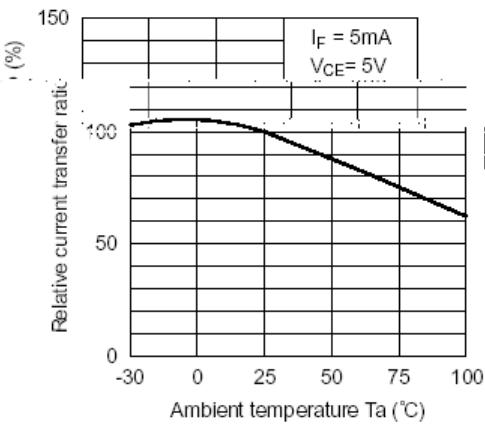


Fig.8 Collector-emitter Saturation Voltage vs. Ambient Temperature

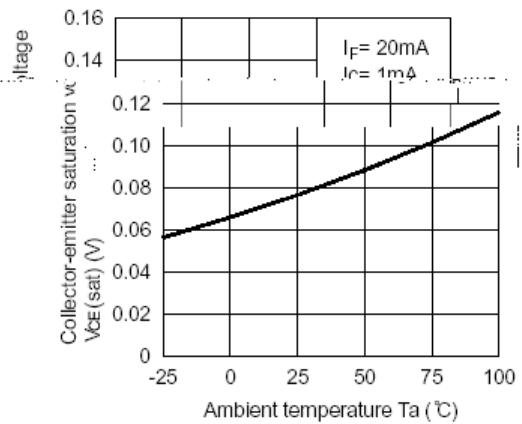


Fig.9 Collector Dark Current vs. Ambient Temperature

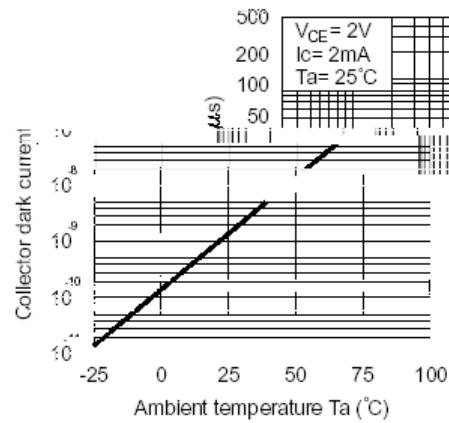
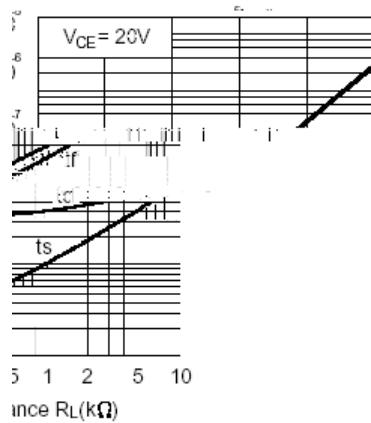
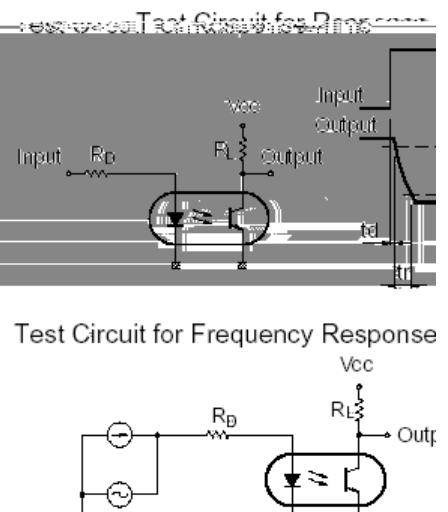
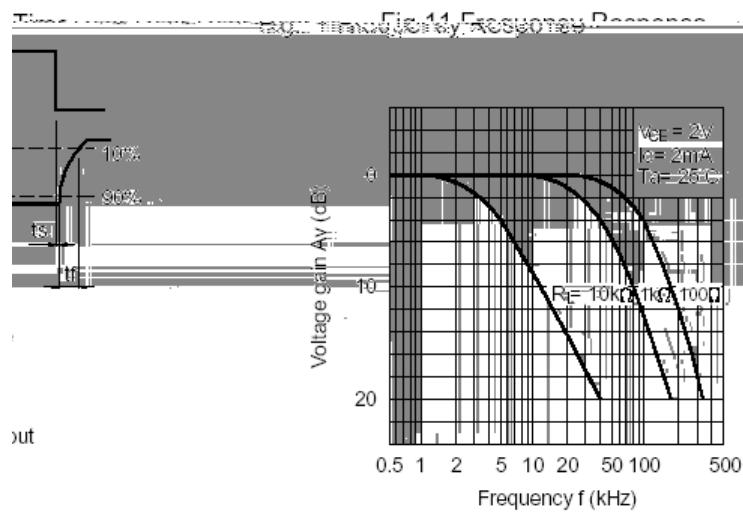
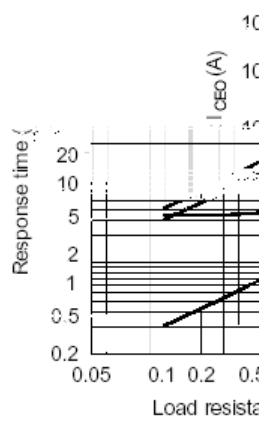


Fig.10 Response Time vs. Load Resistance





BPC-817

KJT)À;•E132!!!;C.2!

		MIL-STD-750:1026 MIL-STD-883:1005 JIS C 7021 : B-1 ±5	N J f à T U E . 9 9 4 ; 2 1 1 6 ! I _F =50mA	STD	1000	E	"0/20 D à h o. T U E
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STD021 : B-1